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Determination of magnetic anisotropy constants in Fe ultrathin film on vicinal Si(1 1 1) by anisotropic magnetoresistance

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The epitaxial growth of ultrathin Fe film on Si(111) surface provides an excellent opportunity to investigate the contribution of magnetic anisotropy to magnetic behavior. Here, we present the anisotropic magnetoresistance (AMR) effect of Fe single crystal film on vicinal Si(111) substrate with atomically flat ultrathin $p(2 \times 2)$ iron silicide as buffer layer. Owing to the tiny misorientation from Fe(111) plane, the symmetry of magnetocrystalline anisotropy energy changes from the six-fold to a superposition of six-fold, four-fold and a weakly uniaxial contribution. Furthermore, the magnitudes of various magnetic anisotropy constants were derived from torque curves on the basis of AMR results. Our work suggests that AMR measurements can be employed to figure out precisely the contributions of various magnetic anisotropy constants.

Magnetic anisotropy is not only the origin of long-range-magnetic-order in low dimensional system¹, but also plays a vital role in determining the magnetic properties for magnetically hard, magnetically soft², high-frequency magnetic materials³, ultrahigh density magnetic recording media and spintronic materials. Recently, the growth and magnetic properties of single crystal Fe film on Si(111) surface have been investigated owing to its application in integration of magnetic devices in Si-based technology and new opportunities in spintronics^{4–11}. The research of Fe ultrathin film magnetization has approached down to the atomic level by a powerful spin-polarized scanning tunneling microscopy (SP-STM)^{12–14}. In the case of *bcc* Fe film grown on Si(111) substrate, the six-fold symmetry of magnetic anisotropy energy exists only when magnetization is confined strictly in the Fe(111) plane. A small structural modification is sufficient to destroy the six-fold symmetry as a result of the contributions from other magnetic anisotropy energies^{7,8}. In our previous work, we observed that the six-fold symmetry of the in-plane resonance field for Fe(111) film was changed into the superposition of a four-fold and a two-fold contribution due to the presence of atomic step of the vicinal substrate¹⁵. Furthermore, we also observed some difference between ferromagnetic resonance (FMR) results and magnetization measurements. FMR results demonstrated that the azimuthal angular dependence of in-plane resonance field is a six-fold symmetry with a weak uniaxial contribution, while the remanence of hysteresis loops displays a two-fold one¹⁶. Therefore, the analysis of the magnetic anisotropy and magnetization reversal should be carried out carefully for Fe(111) films on Si(111) substrate.

Up to date, various methods, such as magnetic hysteresis loop measurement, torque measurement¹⁷, ferromagnetic resonance (FMR)⁷, rotational magneto-optic Kerr effect (ROT-MOKE)¹⁸, and magnetic transverse biased initial inverse susceptibility and torque (TBIIST)¹⁹, have been developed to determine the magnetic anisotropy constants. Since the coherent domain rotation magnetization reversal for ultrathin film is not always occurred, especially when the applied field is lower than saturation field, the detailed information regarding the magnetic anisotropy cannot be distinguished precisely from the magnetization hysteresis loops. Alternatively, magnetotransport method has been proved to be an ideal probe of magnetic anisotropy constants in the thin single layer films by anisotropic magnetoresistance (AMR)^{20–26}, which determines the anisotropy field strength by realization of a coherent magnetization reversal (Stoner-Wohlfarth-like). This can be achieved by applying a sufficiently large field to guarantee a true single-domain rotation. Here, we carried out the AMR measurements in ultrathin single crystalline Fe film on vicinal Si(111) substrate. On the basis of AMR curves, the angle between the magnetization

and magnetic field, and hence the normalized magnetic torque can be derived. Finally, the uniaxial magnetic anisotropy, first- and second-order magnetocrystalline anisotropy constants were precisely obtained by fitting the normalized magnetic torque curves. Our work suggests that the extremely sensitive AMR can provide the detailed contributions of various magnetic anisotropy constants, including the first- and second-order magnetocrystalline anisotropy constants, as well as step-induced in-plane uniaxial magnetic anisotropy constant, of ultrathin Fe single crystal film on vicinal Si(111) surface.

Results

Figure 1(a) shows the schematic configuration of the sample and the coordinate system used in our AMR measurements and data analysis. Although the substrate supplier declares that the Si(111) substrate with orientation accuracy is 0.1° (nominal miscut angle $\beta = 0.1^\circ$), a local miscut varies from point to point on the Si surface will take place due to cutting imperfection or mass transport under the direct heating. Recently, we adopted a novel method to tune the terrace width of Si(111) substrate by varying the direction of heating current²⁷. Large scale images ($850 \text{ nm} \times 850 \text{ nm}$) of the Si(111) substrate were employed to determine the local variation of miscut angles. The typical large scale STM images indicates that the narrower terraces are accompanied by a very broad ($>400 \text{ nm}$) terrace width Figure 1(b). From the section line profile along the perpendicular

direction to the terrace steps (Inset of Fig. 1(b)), a single atomic step in Si(111) surface is about 0.30 nm high can be estimated, which is in good agreement with the value reported by Lin et al.²⁸. On the basis of the relation between atomic height h and terrace width w , $\beta = \arctan(h/w)$, the local miscut angle β can be various from 0.04° to 0.30° with a mean miscut angle of 0.10° . The sharp LEED pattern plotted in figure 1(b) demonstrates an atomically flat Si(111)- 7×7 reconstructed surface.

Figure 1(c) illustrates the STM image of the iron silicide template on the Si(111) substrate and the corresponding 2×2 LEED pattern. The iron silicide template comprises of steps separated by the flat $p(2 \times 2)$ reconstructed terraces. Compared with Si(111)- 7×7 reconstructed surface, the step edges in the STM image for $p(2 \times 2)$ iron silicide reconstructed surface are not so sharp owing to the random diffusion of Fe atoms on Si substrate and the intermixing between Fe and Si atoms. The atomically flat terraces are generally used as a template for preparing ultrathin Fe single crystalline film. Fig. 1(d) shows the STM image of the iron deposited on $p(2 \times 2)$ iron silicide (111)/Si(111) surface for 21 ML and the LEED pattern. The LEED pattern indicates that three-fold symmetry still exists even for a thickness reaching 21 ML, suggesting a *bcc* Fe(111) film. The epitaxial relationships between the Fe(111) film, the iron silicide template and the Si substrate are following²⁹: $\text{Fe}(111) \parallel p(2 \times 2)(111) \parallel \text{Si}(111)$ and $\text{Fe}[-1-12] \parallel p(2 \times 2)$ iron silicide

Figure 1 | The schematic configuration of the sample preparation and coordinate system used in AMR measurements and data analysis, and STM images of sample surface. (a) Schematic configuration of the sample and the coordinate system used in our AMR measurements and data analysis; (b) STM image and LEED patterns of 0.1° vicinal Si(111)- 7×7 reconstructed surface; (c) STM image and LEED patterns of 2×2 iron silicide phases obtained at annealing temperature $T_a = 700 \text{ K}$ for 10 min after 1.5 ML Fe deposited on 0.1° vicinal Si(111) surface; (d) STM image and LEED patterns of 21 ML Fe on $p(2 \times 2)/\text{Si}(111)$.

Figure 2 | The angular dependence of magnetocrystalline anisotropy energies. First- (a) and second- (b) order magnetocrystalline anisotropy energy terms for various miscut angles β , respectively.

[-1-12]||Si[11-2]. Owing to the large lattice mismatch, STM topographic image shows that Fe atoms aggregate immediately into three-dimensional (3D) islands. The first stage is the growth of uniformly strained wetting layers, and elastic energy increases fast with film thickness. The constrained film becomes unstable at a critical thickness and three dimensional islands appear for strain relief. With further increasing film thickness, misfit dislocations are introduced to further relieve strain resulting in deeper facets, dome and ridge-trough structures. The section line in the insert of figure 1(d) indicates that the surface corrugation of grainy thin Fe(111) is rather large. In our previous work, the effect of strain at the Fe/FeSi interface on the magnetic anisotropy has been discussed³⁰. Since thickness of Fe film (about 21 ML) is far thicker than the critical thickness, the strain is released, and consequently has no significant influence on magnetic anisotropy constants.

The total free energy density of the system with the external field H is considered as the following formula⁷:

$$E = -\mu_0 M_s \mathbf{H} \cdot \hat{\mu} + K_1 (\alpha_1^2 \alpha_2^2 + \alpha_2^2 \alpha_3^2 + \alpha_3^2 \alpha_1^2) + K_2 (\alpha_1^2 \alpha_2^2 \alpha_3^2) - K_u (\hat{\mu} \cdot \hat{n}_u)^2 + K_d (\hat{\mu} \cdot \hat{n}_d)^2 - K_s (\hat{\mu} \cdot \hat{n}_s)^2 \quad (1)$$

where the first term is the Zeeman energy, $\hat{\mu}$ is the unit vector of the magnetic vector and M_s is the saturation magnetization of Fe (taken as the bulk value 1.74×10^6 A/m); the second and third terms are cubic magnetocrystalline anisotropy energy, α_i represents the directional cosines of the magnetic vector $\hat{\mu}$ with respect to the cubic axes [100], [010] and [001], K_1 and K_2 are the first two cubic magnetocrystalline anisotropy constants; the last three terms sequentially refer to the uniaxial magnetic anisotropy energy, and surface magnetic anisotropy energy and out-of-plane demagnetization energy. K_u , K_d and K_s are the corresponding magnetic anisotropy constants. The unit vector $\hat{n}_u$ with its orientation along the step direction represents the direction of the easy axis of the uniaxial magnetic anisotropy. $\hat{n}_d$ and $\hat{n}_s$ are the unit vectors normal to vicinal (111) film plane and the (111) plane, respectively. It should be noted that the unit vector $\hat{n}_d$ is perpendicular to the vicinal plane, which is different from a simple flat thin (111) crystal plane with its hard axis of the out-of-plane.

Figures 2 (a) and (b) present the angular dependence of the first- and second-order magnetocrystalline anisotropy energy terms in the Fe(111) plane along [11-2] with various miscut angles, where $K_1 = 4.5 \times 10^4$ J/m³ and $K_2 = 0.05K_1$ ¹⁶, respectively. We can find that the K_1 energy term is invariable (solid line circle in Fig. 2(a)) and the K_2 energy term is six-fold symmetry in exact Fe(111) plane, i.e. miscut angle $\beta = 0^\circ$. However, the K_1 energy term can be changed to a four-fold symmetry by a slight misorientation from (111) plane, i.e. $\beta \neq 0^\circ$. Figure 2(b) demonstrates that the symmetry of the K_2 energy term keeps unchanged.

Since the magnetization reversal process is largely governed by the symmetry, magnitudes and directions of the competing magnetic

anisotropy energies, the symmetry of magnetic anisotropy energy is usually probed by magnetic hysteresis loop. The MOKE hysteresis loops at various angles φ_H between the [-110] axis and magnetic field H , indicate that the easy axis is perpendicular to the step direction, $\varphi_H = 90^\circ$ (Fig. 3(a)). Similar phenomena have been reported in the system Fe/W(001) or Au/Co/Cu/Si(111), which have been explained by the step-induced anisotropy^{31,32}. Unfortunately, owing to the small coercivity (<10 Oe) in the sample, only the two-fold symmetry in remanence and coercivity can be confirmed from figures 3(b) and 3(c), respectively. The contribution of magnetocrystalline anisotropy constants K_1 and K_2 cannot be determined from MOKE measurements.

In order to figure out the magnetocrystalline anisotropy constants K_1 and K_2 , we carried out the AMR measurements. We found that the resistances of Si substrate with and without iron silicide buffer layer, which are almost the same values, are quite larger than the resistance of Fe ultrathin film. Furthermore, the Si substrate and iron silicide buffer layer have no contribution to AMR. Therefore, the metallic Fe single crystal film grown on iron silicide buffer layer and Si(111) surface provides an ideal system to perform AMR measurements. In the case of Fe single-crystalline system, the AMR can be expressed as^{20–26}:

$$R_{xx} = R_\perp + (R_\parallel - R_\perp) \cos^2 \varphi_M \quad (2)$$

where φ_M is the angle between the Fe magnetization M_{Fe} and the current flow I , $R_\parallel$ and $R_\perp$ is the resistance at $\varphi_M = 0^\circ$ and $\varphi_M = 90^\circ$, respectively.

Figure 4(a) shows the angular dependence of the in-plane AMR with different applied fields. The external magnetic fields are larger than saturation field to guarantee a true single-domain rotation and eliminate the ordinary magnetoresistance effect. During rotation of the sample, the AMR values show an oscillated behavior between the maximum value $R_\parallel$ and minimum value $R_\perp$, respectively. However, owing to the magnetic anisotropy, M_{Fe} is no longer kept along with the external field H during rotation, i.e. $\varphi_M < \varphi_H$. Therefore, the AMR curves do not follow the $\cos^2 \varphi_H$ relationship. The correlation between φ_H and φ_M can be obtained from Fig. 4 (a) and plotted in Fig. 4 (b).

On the basis of the angle difference between φ_H and φ_M , we can further calculate the magnetic torque $L(\varphi_M) = \mu_0 M_s H \sin(\varphi_H - \varphi_M)$ curves from Fig. 4(b) at different external fields. In order to compare magnetic torques at different fields, the normalized magnetic torque $l(\varphi_M) = L(\varphi_M) / \mu_0 M_s H = \sin(\varphi_H - \varphi_M)$ was introduced. As shown in figure 5(a), the normalized magnetic torque curves exhibit different shapes with different external field H . In equilibrium state, the torque acting on M_{Fe} due to H is equal in magnitude to the torque due to the magnetic anisotropies of the sample. Since the demagnetization field is normal to the Si(111) plane, its contribution to the magnetic torque is zero. According to Eq.(1), the normalized magnetic torque can be written as:

$$l(\varphi_M) = \left\{ K_1 \times \left[\sin 4\varphi_M \left(\frac{3}{8} \sin^4 \gamma - \frac{1}{2} \cos^2 \gamma \right) + \sin 2\varphi_M \left(\frac{1}{2} \sin^2 \gamma \cos^2 \gamma - \frac{1}{4} \sin^4 \gamma \right) \right] + K_2 \times \left[\sin 6\varphi_M \left(\frac{3}{64} \sin^6 \gamma + \frac{3}{16} \sin^2 \gamma \cos^2 \gamma \right) + \sin 4\varphi_M \left(\frac{3}{16} \sin^4 \gamma \cos^2 \gamma + \frac{1}{16} \sin^4 \gamma - \frac{1}{4} \sin^2 \gamma \cos^2 \gamma \right) + \sin 2\varphi_M \left(-\frac{1}{16} \sin^2 \gamma \cos^2 \gamma + \frac{7}{64} \sin^6 \gamma + \frac{1}{8} \sin^4 \gamma \cos^2 \gamma \right) + \frac{1}{4} \sin^2 \gamma \cos^4 \gamma - \frac{1}{8} \sin^4 \gamma \right] + K_u \times [\sin 2\varphi_M] - \frac{1}{3} K_s \sin 2\varphi_M (\sqrt{2} \sin 2\gamma + \cos^2 \gamma + 1) \right\} / \mu_0 M_s H \quad (3)$$

Figure 3 | The typical hysteresis loops and angular dependence of in-plane magnetic coercivity and remanence. Experimental hysteresis loops at 0 and 90 deg. (a), angular dependence of in-plane magnetic coercivity (b) and remanence (c) by means of MOKE.

Figure 4 | The in-plane AMR curves at different curves and the correlation between φ_H and φ_M . Angular dependence of the in-plane AMR (a), and the correlation between φ_H and φ_M at different fields (b).

where $\gamma = -\arccos(1/\sqrt{3}) + \beta$, β is the miscut angle of the substrate.

Although the value of K_s ($\sim 10^6$ J/m³) is far larger than that of K_u ($\sim 10^2$ J/m³) for ultrathin Fe film^{15,16}, we can calculate from Eq.(3) that the value of torque contributed by K_s is at least two order of magnitude smaller than that contributed by K_u . Therefore, the contribution of surface anisotropy constant to the torque can be neglected.

It can obviously from Eq.(4) that the magnetic torque shows a superposition of two-, four- and six-fold magnetic anisotropies from the step-induced uniaxial magnetic anisotropy K_u , the first-order magnetocrystalline constant K_1 and the second-order magnetocrystalline anisotropy constant K_2 , respectively. The two-fold symmetry disappears gradually with increasing external field H , suggesting that the strength of K_u is very weak. Therefore, in order to distinguish the contribution from K_u , the external field H should be kept slightly larger than the saturation field.

From Eq.(3), we can obviously find that the normalized torque $l(\varphi_M)$ is significantly affected by the substrate's miscut angle β . The tendency of the anisotropy energy is complicated. We can find that the four-fold anisotropy energy changes significantly (Fig. 2(a)), while the six-fold anisotropy energy almost does not change with the miscut angle β (Fig. 2(b)). In the case of $\beta = 0.0^\circ$, the K_1 term is zero. Usually the miscut angle of the substrate cannot be neglected, and thus the contribution from the first-order magnetocrystalline anisotropy constant in vicinal (111) plane must be taken into account.

In order to investigate the tiny variation of miscut angles on the fitting parameters, Figure 6 illustrates the fitted magnetic anisotropy constants for various miscut angles β from -0.30° to 0.30° . It is noteworthy that a tiny variation of miscut angles β has no effect on the values of K_2 and K_u (Figure 6(a)), whereas significantly affects the fitted values of the first-order magnetocrystalline anisotropy K_1 (Figure 6(b)). Since the global AMR properties are measured for the whole sample, the use of the mean miscut angle of Si(111) of

Figure 5 | The normalized magnetic torque curves. Normalized magnetic torque curves superposed by the first- and second-order magnetocrystalline anisotropies and uniaxial anisotropy at different fields (a) and the normalized torque contributed only by the first- and second-order magnetocrystalline anisotropies at field of 1600 A/m (b), the solid lines are fitting curves. For comparison, the normalized magnetic torque curves were also plotted in Figure 5(a).

about 0.10° is reasonable. The fitted value of $K_1 = 3.4 \times 10^4$ J/m³ is comparable with the value of $K_1 = 4.5 \times 10^4$ J/m³ for bulk *bcc*-Fe.

The AMR results are consistent with the fitting results from FMR, where $K_1 = 4.4 \times 10^4$ J/m³, $K_2 = 2.2 \times 10^3$ J/m³ and $K_u = -5.9 \times 10^2$ J/m³ for 45 ML Fe film on Si(111)¹⁶. For comparison, we also measured the 45 ML Fe sample in Ref. 16 by FMR to cross-check the measured anisotropy constant obtained by AMR. As shown in figure 5(a), the magnetic anisotropy constants $K_1 = 4.4 \times 10^4$ J/m³, $K_2 = 2.1 \times 10^3$ J/m³ and $K_u = -1.1 \times 10^3$ J/m³ can be obtained. Both AMR and FMR give almost same values of K_1 and K_2 , while the absolute value of K_u obtained by AMR are slightly larger. A careful comparison between these two techniques to measure the magnetic anisotropy constants is in progress.

The negative value of K_u suggests that the easy axis is perpendicular to the step direction, which is in good agreement with the hysteresis loops (Fig. 3 (a)). By using the magnetic anisotropy constants, the angular dependence of coercivity and remanence were also simulated in term of coherent rotation magnetization reversal, as illustrated in Figs. 3(b) and (c), respectively. We can observe that the calculated remanence is consistent with experimental one, whereas the calculated coercivity deviates the experimental one significantly in the easy axis direction. The significant deviation implies that the magnetization reversal is not governed by coherent rotation, and consequently, magnetic hysteresis loop cannot provide a detailed symmetry of magnetic anisotropy energies.

The contribution of K_1 and K_2 to magnetic torque is about one order of magnitude smaller than that of uniaxial magnetic anisotropy constant K_u . In order to separate their contributions, Fourier analysis

Figure 6 | The fitted magnetic anisotropy constants K_2 and K_u (a), and K_1 (b) for various miscut angles β from -0.30° to 0.30° .

and inverse Fourier transform are used to analyze the torque curve. If we deduct the contribution of the uniaxial magnetic anisotropy constant K_u to the magnetic torque, it is obviously shown in figure 5(b) that the normalized magnetic torque curve $I_{K_1,K_2}(\varphi_M)$ is the superposition of a four-fold and a six-fold anisotropy contributed only from first- and second-order magnetocrystalline anisotropy constants, respectively.

Discussion

We present the MOKE and AMR measurements of Fe single crystal film on 0.1° vicinal Si(111) substrate with atomically flat ultrathin $p(2 \times 2)$ iron silicide as buffer layer. Unfortunately, owing to the small coercivity (<10 Oe) in the sample, only the two-fold symmetry in remanence and coercivity can be observed, while the contribution of magnetocrystalline anisotropy constants K_1 and K_2 cannot be determined from MOKE measurements. On the other hand, the AMR results demonstrate that the symmetry of magnetocrystalline anisotropy energy changes from the six-fold to a superposition of six-fold, four-fold and a weakly uniaxial contribution due to the tiny misorientation from Fe(111) plane. Although the use of AMR to measure the magnetic anisotropy was introduced long time ago^{20–26}, to our knowledge, a precise determination of various magnetic anisotropy constants of Fe(111) film on Si(111)- 7×7 surface with so small miscut angle was not reported in literature. The fitted value of the first-order magnetocrystalline anisotropy K_1 is significantly influenced by the tiny variation of miscut angles β . On the other hand, the values of K_2 and K_u are unchanged. Our work suggests that the AMR measurements can precisely separate the detailed contributions of various magnetic anisotropy constants of single crystalline Fe ultrathin film grown on vicinal Si(111) surface.

Methods

The sample was prepared on Si(111) wafers with nominally miscut angle of 0.1° along [11-2] using an ultrahigh vacuum molecular beam epitaxial chamber (MBE) equipped with the scanning tunneling microscope (STM) and low-energy electron diffraction (LEED). The base pressure of MBE is kept around 2×10^{-10} mbar and all the experiments were conducted at room temperature. After a well-established procedure^{15,16}, the well-defined reconstructed Si(111)- 7×7 surface was obtained. The buffer layer was deposited on the wafers for 1.5 ML of Fe (99.999% purity) heated by e-beam bombardment with a deposition rate of 1.5 ML/min, then annealed at 700 K

for 10 min. This procedure gives a highly ordered 2×2 periodic iron silicide structure to prevent the Fe/Si intermixing⁶. Fe film with thickness of 21 ML was deposited on the iron silicide template. The STM (VT-STM) measurements were performed at the Si substrate, iron silicide template and the Fe film. A non-magnetic NaCl with thickness of 14 ML was deposited on the sample as a capping layer to protect samples oxidation.

The MOKE measurements were carried out at room temperature and described in detail elsewhere^{15,16}. The home-made AMR setup consists of a Wheatstone bridge, a Lock-in amplifier (Stanford Research Systems SR830 DSP), a temperature controller (Stability $< 0.0012^\circ\text{C/h}$), and a rotational sample stage. Magnetic field is provided by a Helmholtz coil. In the experiments, a sufficiently large and stable field is applied to guarantee a true single-domain behavior of the specimen. The application of Wheatstone bridge and highly stable temperature controller ensures the sensitivity of AMR better than 0.01% in the entire measurements. The sample size is $3 \text{ mm} \times 5 \text{ mm}$ for AMR measurements, which were performed with a standard four-point method.

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Author contributions

Z.H.C., J.Y., W.H., Q.W. and H.L.L. planned the experiments. J.Y. and Q.W. carried out the experiments. All the co-authors contributed to the analysis and discussion for the results. Z.H.C. and J.Y. wrote the paper with the input from all the co-authors.

Additional information

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